



# **High IIP3 PIN Diode Variable Attenuator** 1.70-2.00 GHz

MA4VAT2004-1061T

#### **Features**

- RoHs and ELV compliant
- 1.4 dB Insertion Loss, Typical
- 1.4:1 VSWR, Typical
- 21 dB Attenuation, Typical
- 45 dBm IIP3, Typical (1 MHz Offset, @ + 0 dBm Pinc)
- 0 1.66 Volts Control Voltage @ 1.50 mA Typical

#### Extra Features

- Covers the following Bands:
  - DCS
  - PCS
  - UMTS/WCDMA/CDMA
  - TD-S\_CDMA
  - SCDMA
- Usable Bandwidth: 1.50 GHz to 2.50 GHz
- 1.8 dB Insertion Loss, Typical
- 2:1 VSWR, Typical
- 18.5 dB Attenuation, Typical

### **Description and Applications**

M/A-COM's MA4VAT2004-1061T is a HMIC PIN Diode Variable Attenuator which utilizes an integrated 90 degree 3dB hybrid with a pair of Silicon PIN Diodes to perform the required attenuation function as D.C. Voltage (Current) is applied.

This device operates from 0 to 1.66 Volts at 1.50mA typical control current for maximum attenuation. The user can add external biasing resistors to the bias ports for higher voltage requirements as required.

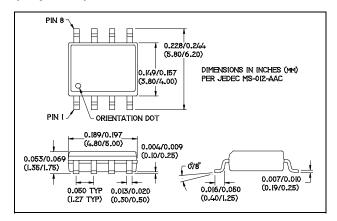
M/A-COM's MA4VAT2004-1061T PIN Diode Variable Attenuator is designed for AGC Circuit Applications requiring:

Lower Insertion Loss

information.

- Lower distortion through attenuation
- Large dynamic range for wide spread spectrum applications

# **PIN Configuration** (Topview)



### **PIN Configuration (Topview)**

| PIN | Function | Comments                     |  |  |
|-----|----------|------------------------------|--|--|
| 1   | DC1      |                              |  |  |
| 2   | GND      |                              |  |  |
| 3   | GND      |                              |  |  |
| 4   | RFin/out | Symetrical as RF Input/Ouput |  |  |
| 5   | RFout/in | Symetrical as RF Input/Ouput |  |  |
| 6   | GND      |                              |  |  |
| 7   | GND      |                              |  |  |
| 8   | DC2      |                              |  |  |

# Absolute Maximum Ratings<sup>1,2</sup> @ $T = +25 \, ^{\circ}C$

| Parameter                | Maximum Ratings   |  |  |
|--------------------------|-------------------|--|--|
| Operating Temperature    | -40 °C to +85 °C  |  |  |
| Storage Temperature      | -65 °C to +150 °C |  |  |
| Junction Temperature     | +175 °C           |  |  |
| RF C.W. Incident Power   | +33 dBm C.W.      |  |  |
| Reversed Current @ -30 V | I -50nA I         |  |  |
| Control Current          | 50mA per Diode    |  |  |

1. All the above are at Room Temperature except as noted

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- 2. Exceeding the above Limits may cause permanent damage
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## Electrical Specifications @ +25 °C

| Parameter                            | Frequency Band      | Unit | Min | Тур            | Max |
|--------------------------------------|---------------------|------|-----|----------------|-----|
| No DC Bias Low Loss State            |                     |      |     |                |     |
| Insertion Loss                       | 1.70 GHz – 2.00 GHz | dB   | -   | 1.4            | 1.8 |
| Input Return Loss                    |                     | dB   | 13  | 15             | -   |
| Output Return Loss                   |                     | dB   | 13  | 15             | -   |
| P1dB                                 |                     | dBm  | 30  | -              | -   |
| IIP3                                 |                     | dBm  | 47  | 49             | -   |
| Control Voltage                      |                     | V    | -   | 0V @ 0uA       | -   |
| DC Bias RF Attenuation State         |                     |      |     |                |     |
| Maximum Attenuation                  | 1.70 GHz – 2.00 GHz | dB   | 20  | 24             | -   |
| Input Return Loss @ Max Attenuation  |                     | dB   | 18  | 21             | -   |
| Output Return Loss @ Max Attenuation |                     | dB   | 18  | 21             | -   |
| IP3                                  |                     | dBm  | 36  | 39             | -   |
| Control Voltage @ Max Attenuation    |                     | V    | -   | 1.66V @ 1.50mA | -   |

# Typical RF Performance Over Industry Designated RF Frequency Bands

| Band       |    | Freq      | I. Loss | Att. | R. Loss | IIP3  | Phase<br>-Relative- |
|------------|----|-----------|---------|------|---------|-------|---------------------|
|            |    | (MHz)     | (dB)    | (dB) | (dB)    | (dBm) | (Degree)            |
| DCS        | RX | 1710-1785 | 1.6     | 22   | 13      | 50    | +150                |
|            | TX | 1805-1880 | 1.6     | 22   | 13      | 50    |                     |
|            |    |           |         |      |         |       |                     |
| PCS        | RX | 1850-1910 | 1.6     | 21   | 13      | 50    | +10°                |
|            | TX | 1930-1990 | 1.6     | 21   | 13      | 50    |                     |
|            |    |           |         |      |         |       |                     |
| UMTS       | RX | 1920-1980 | 1.6     | 20   | 13      | 50    | -5°                 |
| WCDMA/CDMA | TX | 2110-2170 | 1.8     | 20   | 13      | 50    |                     |
|            |    |           |         |      |         |       |                     |
| TD-S-CDMA  | -  | 2010-2025 | 1.7     | 20   | 13      | 50    | -2°                 |
|            |    |           |         |      |         |       |                     |
| SCDMA      | -  | 1800-2200 | 1.8     | 20   | 13      | 50    | -10°                |

<sup>1.</sup> All are typical values only.

information.

<sup>2.</sup> Relative phase is the measured Insertion Phase Difference between Insertion Loss and the 20dB Attenuation State. (Please refer to the plots below)

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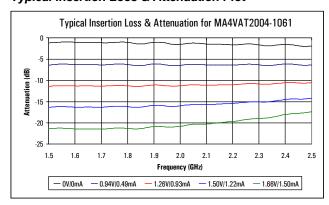


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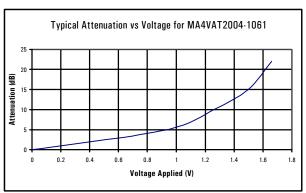
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# Plots of Typical RF Characteristics @ + 25 °C

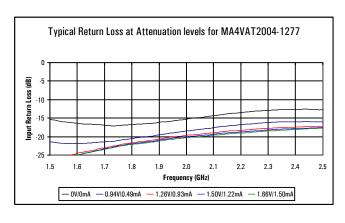
#### **Typical Insertion Loss & Attenuation Plot**



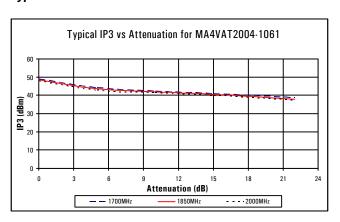
#### Typical Attenuation Vs Voltage Plot



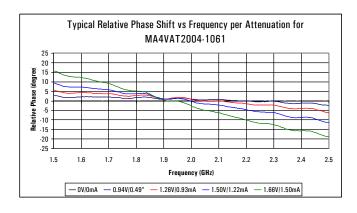
#### Typical Return Loss @ All Attenuation Levels Plot



#### Typical IIP3 Vs Attenuation Plot



# Typical Relative Phase Shift Per Attenuation (Voltage) Plot



#### For Reference ONLY:

Low Loss = 0.00V, @0.00mA
5 dB Attenuation = 0.94V, @0.49mA
10 dB Attenuation = 1.26V, @0.93mA
15 dB Attenuation = 1.50V, @1.22mA
20 dB Attenuation = 1.66V, @1.50mA

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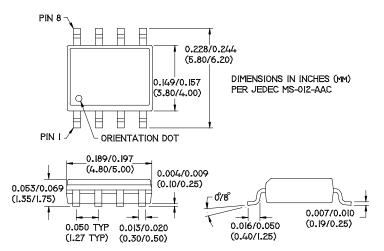


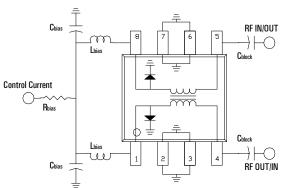


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#### Package Pin Designation, External Components, and Equivalent Circuit





#### **External Bias Components**

Rbias= 680 Ohms ( 1.66 V, 1.50 mA ) Lbias= 150 nH Cbias =100 pF Cblock =100 pF

### **Ordering Information**

| Part Number      | Package       |  |  |
|------------------|---------------|--|--|
| MA4VAT2004-1061T | Tape and Reel |  |  |

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